Solutions Manual for **[RF Microelectronics](https://testbankdeal.com/download/rf-microelectronics-2nd-edition-razavi-solutions-manual/)**

Second Edition

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RF Microelectronics, Second Edition

Errata

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- Prob. 2.3, second line should read: consider the cascade of identical ...
- Fig. 3.10 should be changed as shown below:

Fig. 4.81(a) should be changed as shown below:

- Example 4.36, the first sentence in solution should read: We have $V_{out1} = (1/2)(1 j)V_1$ and ...
- Example 5.5, third line in solution: Since it is desired that $R_{in} = R_S$,
- Example 6.21, last three lines of solution: Note that $V_{n2}(f)$ is typically very large because M_2 and M_3 are relatively small.
- Example 7.6, Eq. (7.33) should read:

$$
C_{eq} = \frac{C_1 + \dots + C_{4(N-1)}}{[4(N-1)]^2} \tag{1}
$$

Eq. (7.125) in Problem 7.3 must also be corrected as above.

- p. 488, the sentence below Eq. (7.114) should read $Z_1d = R_{tot}/2$ and $Y_1d = C_{tot}s/2$.
- Prob. 7.10, Assume the inductance is about 9 times that of one spiral.
- Fig. 8.84 (b) should be changed as follows:

Fig. 11.45 should be changed as shown below. **Margin to**

Fig. 12.53(b) should be changed as shown below.

$$
= \frac{1}{\sqrt{\frac{1}{A_{\text{int},1}^{2}}}} + \frac{3}{\theta} \frac{2}{\theta} \frac{3}{\theta} \frac{\beta_{2}}{\beta_{1}} + \frac{3}{\theta} \frac{2}{A_{\text{in},2,1}} \frac{2}{\theta_{\text{in}}}
$$

 $\label{eq:2.1} \frac{1}{\sqrt{2}}\int_{\mathbb{R}^3}\frac{1}{\sqrt{2}}\left(\frac{1}{\sqrt{2}}\right)^2\frac{1}{\sqrt{2}}\left(\frac{1}{\sqrt{2}}\right)^2\frac{1}{\sqrt{2}}\left(\frac{1}{\sqrt{2}}\right)^2\frac{1}{\sqrt{2}}\left(\frac{1}{\sqrt{2}}\right)^2.$

2.2 Solve:
\n
$$
0.550
$$
 ming -3dBm A, at 2.42G
\n 35 dBm A₂ at 2.43G.

 $\mathcal{L}^{\text{max}}_{\text{max}}$, where $\mathcal{L}^{\text{max}}_{\text{max}}$

$$
=29.5dBm
$$

$$
\int_{2.3}^{2} 6u \, du = \int_{0}^{160} \frac{1}{k} \int_{0}^{1} \frac{1}{k} \int_{0}^{
$$

 \overline{z} 2.4. Sola.

$$
y(t) = \delta_1 X(t) + \delta_2 X(t) + \delta_3 X^3(t) + \delta_4 X(t) + \delta_5 X^5(t)
$$

\n
$$
y(t) = \delta_1 X(t) + \delta_3 X(t) + \delta_3 X^3(t) + \delta_4 X(t) + \delta_5 X^5(t)
$$

\n
$$
y(t) = \delta_1 X(t) + \delta_3 X(t) + \delta_3 X^3(t) + \delta_4 X^5(t) + \delta_5 X^5(t)
$$

\n
$$
y(t) = \delta_1 X(t) + \delta_2 X(t) + \frac{1}{4} \omega_5 X(t)
$$

\n
$$
y(t) = \delta_1 X(t) + \frac{1}{2} \omega_5 X(t) + \frac{1}{2} \omega_5 X(t)
$$

\n
$$
= (\frac{3}{4} \omega_5 Wt + \frac{1}{8} \omega_5 X(t) + \frac{3}{8} \omega_5 X(t) + \frac{1}{8} \omega_5 X(t) + \frac{1}{8
$$

3rd order
\n
$$
\Rightarrow \frac{1}{4} \partial_3 A^3 + (\frac{1}{8} + \frac{3}{16}) \partial_5 A^5
$$

\n(1) 17dB \Rightarrow 20 log 10, + $\frac{3}{4} \partial_3 A^2 + \frac{5}{8} \partial_5 A^4$ = 20 log 10, -10B
\n \Rightarrow Ain, log = $\sqrt{\frac{0.8 \cdot (\text{0.5625} \sigma_3^2 - 0.2115 \sigma_1 \sigma_5)^2 - 0.6 \sigma_3}{\sigma_5}}$

 (2) IIf3 cloesn't change.

$$
A_{11P3} = \sqrt{\frac{4}{3}|\frac{\partial_1}{\partial_3}|}
$$

$$
2.5 (a) 5olu : A5i = \frac{1}{2} \times \frac{1}{2} \times
$$

 12.6 Solu:

Let XH be a random signal (wide-sense starting by
$$
PIO(0s)
$$
)
Aut's correlation function: $R_x(t) = E[X(t) \cdot X(t+z)]$
let me $Prob\psi$ that : $S_x(f) = \int_{-\infty}^{\infty} R_x(\tau) e^{-i2\pi f z} d\tau$.

$$
Proof: \tX_T(f) \triangleq \int_{-T/2}^{T/2} x(t) e^{-j2\pi ft} dt.
$$

$$
S_T(f) \triangleq E[\frac{1}{T} |x_T(f)|^2]
$$

$$
S_{x}(4) = \lim_{T \to \infty} S_{T}(4),
$$
\n
$$
E[Y_{x_{T}}(4)|^{2}] = E[\int_{-T/2}^{T/2} x(t) e^{-ipx/t} dt]^2
$$
\n
$$
= E[\int_{-T/2}^{T/2} x(t) e^{-ipx/t} dt \cdot \int_{-T/2}^{T/2} x(t) e^{-ipx/t} dt]
$$
\n
$$
= E[\int_{-T/2}^{T/2} f(t) x(t) e^{-ipx/t} dt] dt]
$$
\n
$$
= \int_{-T/2}^{T/2} \int_{-T/2}^{T/2} E[x(t) \cdot x(t)] e^{-ipx/(t-z)} dt dt]
$$
\n
$$
= \int_{-T/2}^{T/2} \int_{-T/2}^{T/2} R_{x}(t-z) e^{-ipx/(t-z)} dt dt.
$$
\n
$$
= \int_{-T}^{T/2} \int_{-T/2}^{T/2} R_{x}(t-z) e^{-ipx/(t-z)} dt dt.
$$
\n
$$
= \int_{-T}^{T} (T - |t|) R_{x}(t) e^{-ix/t} dt.
$$
\n
$$
= \int_{-T}^{T} (T - |t|) R_{x}(t) e^{-ix/t} dt.
$$

There for
$$
f
$$
 or f is $\int x(1) = \lim_{T \to \infty} E[\frac{1}{T} |x_T(f)|^2] = \int_{-\infty}^{+\infty} R_x(\tau) e^{-j2\pi/2} d\tau$

 $\mathcal{A}^{\mathcal{A}}_{\mathcal{A}}$, \mathcal{A}

 $-$ 27. Solu:

Assume $y(t) = \frac{\partial}{\partial x}x(t) + \frac{2}{\partial y}x(t) + \frac{3}{\partial z}x(t)$ $x(t) = k \omega s w_0 t$ $3rd = \text{harmonic}$ $\frac{83 \text{ V}_{o}^{3}}{\frac{1}{4}}$ = V_{3} \Rightarrow $\partial_3 = \frac{4v_3}{k^3}$ $A_{in,1ab} = \sqrt{0.445 \left| \frac{\partial I}{\partial x} \right|}$ $=$ $\sqrt{0.145\sqrt{9/46}}u^3$ $=$ $\sqrt{\frac{0.145}{4} \frac{\partial_1 V_0^3}{V_2}}$

 $\sim 10^{11}$

12.8 $s0/u$:
 $\frac{1}{2}R_1$ $\frac{1}{2}R_2$ $\frac{1}{2}R_3$ $\frac{4kT}{R_2}$ $P_{R_1} = \frac{1}{\hat{i}_1^2} R_1$ = $\sqrt{\frac{4kT}{R_{2}}} \cdot \frac{k_{2}}{R_{1}tR_{2}}$, R, = $\frac{4kT}{(R_1+R_2)}$ R_1R_2 \therefore P_{R_1} = P_{R_2} So it proves that noise power delivered by R, to R2 is equal to that delivered by R_2 for R_3 at the Same temperature

If it is not the truck, the energy would not be conserved

 12.9 Solu:

Why the channel thermal noise of a MOSFET is model by a current source bu. S & P. rather than $G \& D$.

Firstly, from the figure we can find the channel

Vesistor is between source & drain. As a result, it is reasonable to model the noise by a current source between source and drain.

Secondly, MosFET has the function of transconductance. It's easy to transfer the current source from buteen SSLD to the voltage source at the gate.

 \perp 2.10 ω

 $\mathcal{L}_{\mathcal{L}}$

Proof: transformductance: 9m.
\nAssume the transistor is in saturation region.
\nFor small-signal analysis,
$$
V_i = 0
$$

\n $I_p = \sqrt{\frac{1}{2n}} = \sqrt{4kT} \sqrt{9m}$.
\nAt the same time for voltage counts in 11

At the same time, for voltage source model.
\n
$$
I_{D} = V_{in}^{*}: J_{m} = \sqrt{4kT} \delta_{.}^{*} J_{m}
$$
\n
$$
\Rightarrow V_{in} = \sqrt{\frac{4kT \delta}{.}} J_{m}
$$
\n
$$
\Rightarrow \overline{V_{n}^{2}} = \frac{4kT \delta}{.} J_{m}
$$

 $\mathcal{L}^{\text{max}}_{\text{max}}$ and $\mathcal{L}^{\text{max}}_{\text{max}}$

Because ne cannot find any loop for the current thrugugh R. $V_5 = 0$

 \hat{A}^{\dagger} , \hat{A}^{\dagger}

 \Rightarrow $\frac{V_{\text{out}}}{V_{\text{o}}} = -I_n$ V_{out} = - $J_n \cdot r_o$

 $\frac{1}{\sqrt{2}} = \frac{1}{2} \sqrt{2}$

 $12.13.$ Sohi: Hegliet. transistor cap.
Hegliet. transistor cap.
CLM. body effect. For Ist Stage: $R_{in1} = \frac{1}{3m_1}$, $R_{h2} = \infty$,
 $\overline{V}_{n_1}^2 = 4kT R_{D1} + \frac{4kT\delta}{3m_1} (\frac{R_{D1}}{3m_1}T^2) = \frac{V_{2}T^2}{3m_1}T^2$, unloaded output noise.

For 2nd stage:
\n
$$
\frac{1}{V_{nz}} = 4k7R_{02} + 4k7\delta \cdot g_{m3}R_{02}^{2}
$$
\nWe now substitute these values in Eq. (2.126)
\n
$$
NF_{tot} = 1 + \frac{4kTR_{01} + 4kT_{mm}^2}{\frac{4}{3m_1} + R_5} \cdot \frac{R_{DL}}{g_{m_1} + R_5} \cdot \frac{1}{4k7R_5}
$$
\n
$$
+ \frac{4kTR_{0} + 4k7\delta \cdot g_{m2} \cdot R_{02}^{2}}{(\frac{4}{3m_1} + R_5)^{2} (g_{m_1} \cdot R_{01})^{2}} \cdot \frac{1}{4k7R_5}
$$
\n
$$
+ \frac{4k7R_{0} + 4k7\delta \cdot g_{m2} \cdot R_{02}^{2}}{(\frac{4}{3m_1} + R_5)^{2} (g_{m_1} \cdot R_{01})^{2} \cdot (g_{m_2} \cdot R_{02})} \cdot \frac{1}{4k7R_5}
$$

This result is different from the cs + cs configuration because. The first stage is NF and input impedance are different, which affect the NF_{tot} .

$$
1 + \frac{4kT \delta g_{m} r_{o1}}{(g_{m,r_{o1}})^{2}} \cdot \frac{1}{4kTR_{s}}
$$
\n
$$
+ \frac{4kT \delta g_{m} r_{o1}}{(g_{m,r_{o1}})^{2}} \cdot \frac{1}{4kTR_{s}}
$$
\n
$$
+ \frac{4kT \delta g_{m} r_{o2}}{(g_{m,r_{o1}})^{2} \cdot (\frac{1}{g_{m}r^{2}})^{2}} \cdot \frac{1}{4kTR_{s}}
$$
\n
$$
1 + \frac{1}{2kTR_{s}}
$$
\n
$$
1 +
$$

now substitute these values in Eq. (2126) We

2.15 Solve:
\n
$$
\frac{1}{2}R_c
$$
\n